

N-Channel 80 V (D-S) Super Junction MOSFET

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ)(TYP.)	I _D (A)	Q _g (TYP.)
80	1.6 at V _{GS} = 10 V	290	155 nC

FEATURES

- DT-TrenchPower MOSFET
- 100 % R_g and UIS tested
- Improved dv/dt capability

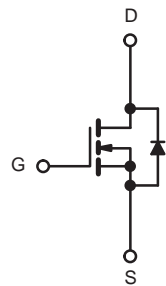
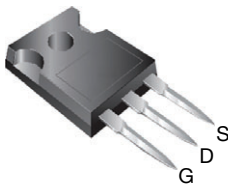


RoHS
COMPLIANT

APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- Hard Switched and High Frequency Circuits

TO-247AC



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		LIMIT	UNIT	
Drain-Source Voltage	V _{DS}	80	V	
Gate-Source Voltage	V _{GS}	± 20		
Continuous Drain Current (T _J = 150 °C)	T _C = 25 °C	I _D	290	
	T _C = 100 °C		165	
Pulsed Drain Current (t = 100 μs)	I _{DM}	1200	A	
Avalanche Current	L = 0.1 mH	I _{AS}	170	
Single Avalanche Energy ^a		E _{AS}	1310	mJ
Maximum Power Dissipation ^a	T _C = 25 °C	P _D	420 ^b	W
	T _C = 125 °C		84 ^b	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C	

THERMAL RESISTANCE RATINGS

PARAMETER		LIMIT	UNIT
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	62	°C/W
Junction-to-Case (Drain)	R _{thJC}	0.42	

Notes

- Duty cycle ≤ 1 %.
- See SOA curve for voltage derating.
- When mounted on 1" square PCB (FR4 material).

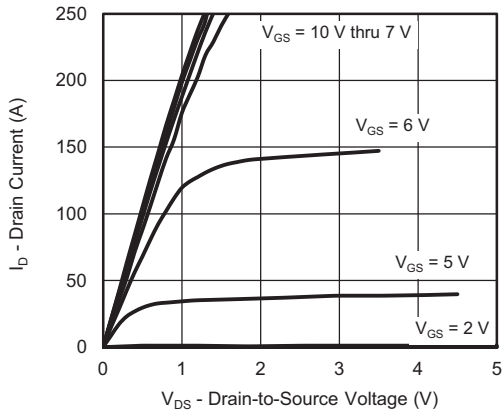
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	80	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1.2	-	2.5	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}$	-	-	1	μA
		$V_{DS} = 64\text{ V}, V_{GS} = 0\text{ V}, T_J = 85\text{ }^\circ\text{C}$	-	-	10	
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 20\text{ A}$	-	1.6	1.98	m Ω
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15\text{ V}, I_D = 3\text{ A}$	-	18	-	S
Dynamic ^b						
Input Capacitance	C_{iss}	$V_{GS} = 0\text{ V}, V_{DS} = 40\text{ V}, f = 1\text{ MHz}$	-	9750	-	pF
Output Capacitance	C_{oss}		-	2030	-	
Reverse Transfer Capacitance	C_{rss}		-	77	-	
Total Gate Charge ^c	Q_g	$V_{DS} = 40\text{ V}, V_{GS} = 10\text{ V}, I_D = 30\text{ A}$	-	155	-	nC
Gate-Source Charge ^c	Q_{gs}		-	32	-	
Gate-Drain Charge ^c	Q_{gd}		-	73	-	
Gate Resistance	R_g	$f = 1\text{ MHz}$	-	1.0	-	Ω
Turn-On Delay Time ^c	$t_{d(on)}$	$V_{DD} = 40\text{ V}, R_L = 1.67\text{ }\Omega$ $I_D = 30\text{ A}, V_{GEN} = 10\text{ V}, R_g = 1\text{ }\Omega$	-	20	-	ns
Rise Time ^c	t_r		-	16	-	
Turn-Off Delay Time ^c	$t_{d(off)}$		-	47	-	
Fall Time ^c	t_f		-	55	-	
Drain-Source Body Diode Ratings and Characteristics ^b ($T_C = 25\text{ }^\circ\text{C}$)						
Pulsed Current ($t = 100\text{ }\mu\text{s}$)	I_{SM}		-	-	1200	A
Forward Voltage ^a	V_{SD}	$I_F = 30\text{ A}, V_{GS} = 0\text{ V}$	-	-	1.0	V
Reverse Recovery Time	t_{rr}	$I_F = 30\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$	-	105	-	ns
Peak Reverse Recovery Charge	$I_{RM(REC)}$		-	7	-	A
Reverse Recovery Charge	Q_{rr}		-	310	-	nC

Notes

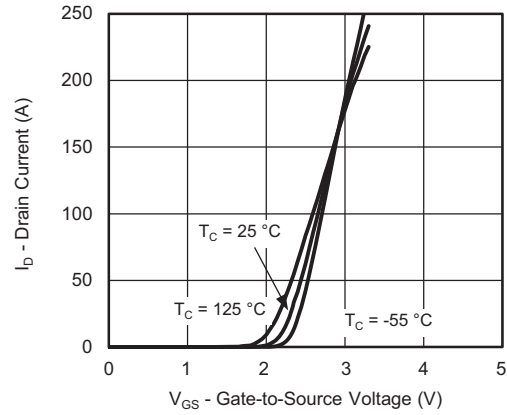
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

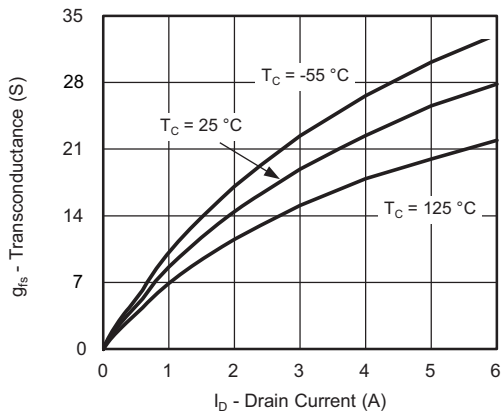
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



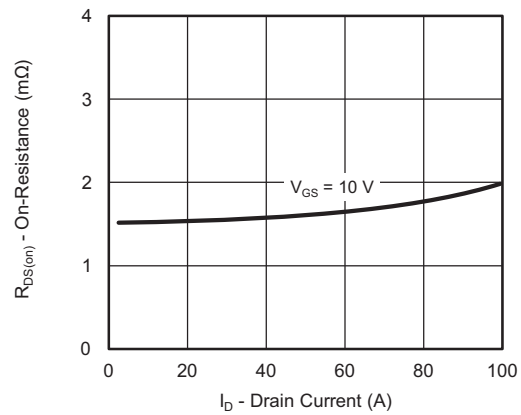
Output Characteristics



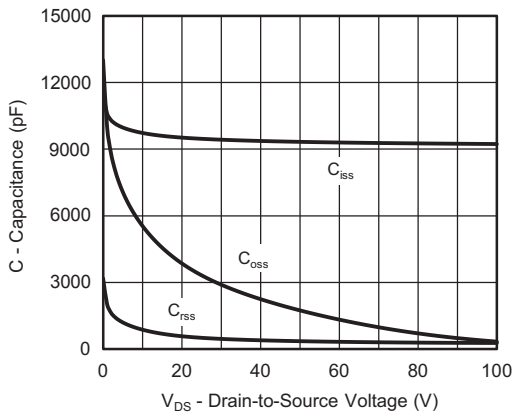
Transfer Characteristics



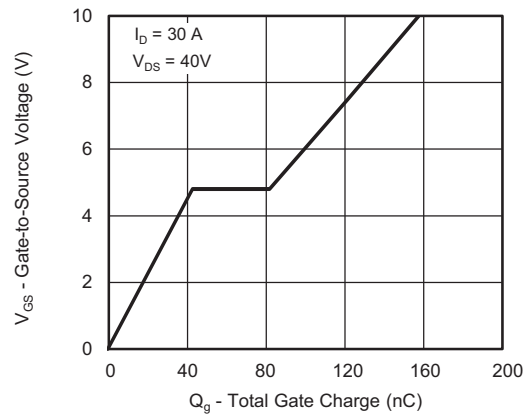
Transconductance



On-Resistance vs. Drain Current

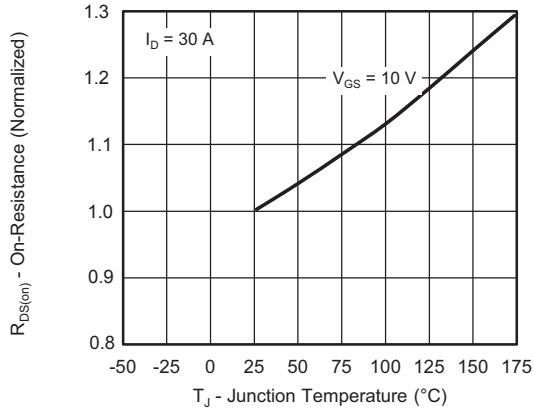


Capacitance

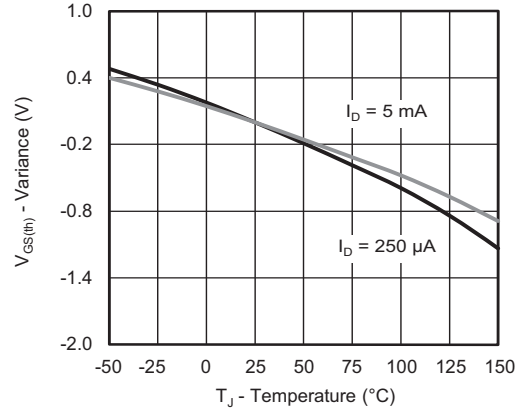


Gate Charge

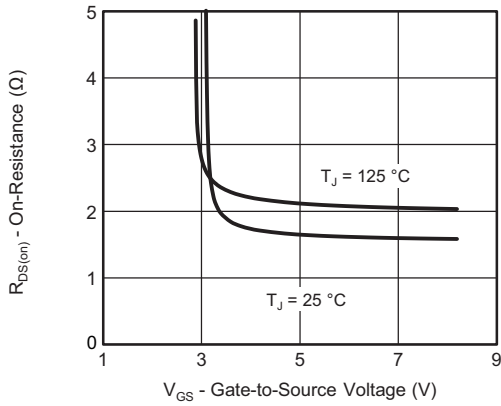
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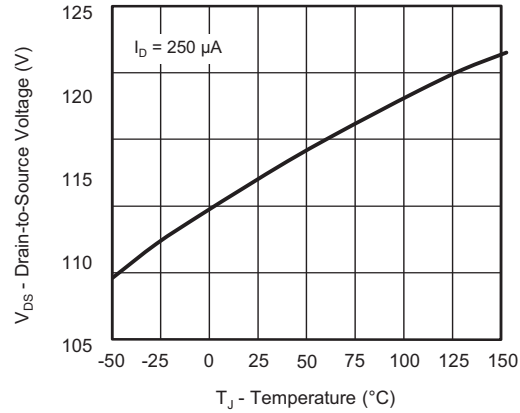
On-Resistance vs. Junction Temperature



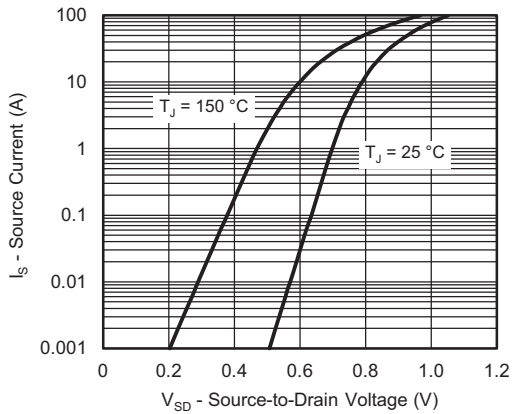
Threshold Voltage



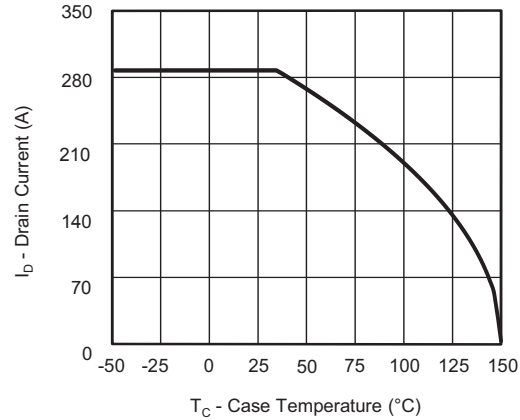
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

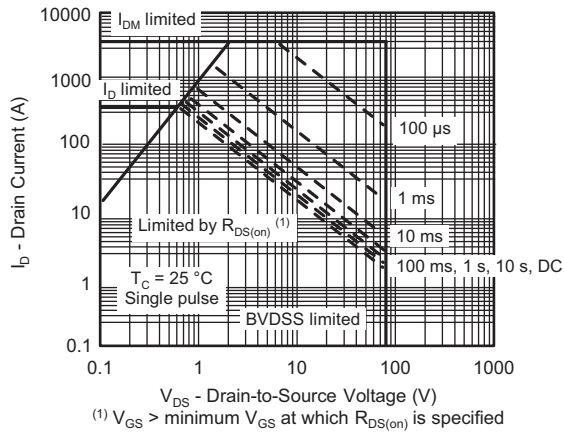


Source Drain Diode Forward Voltage

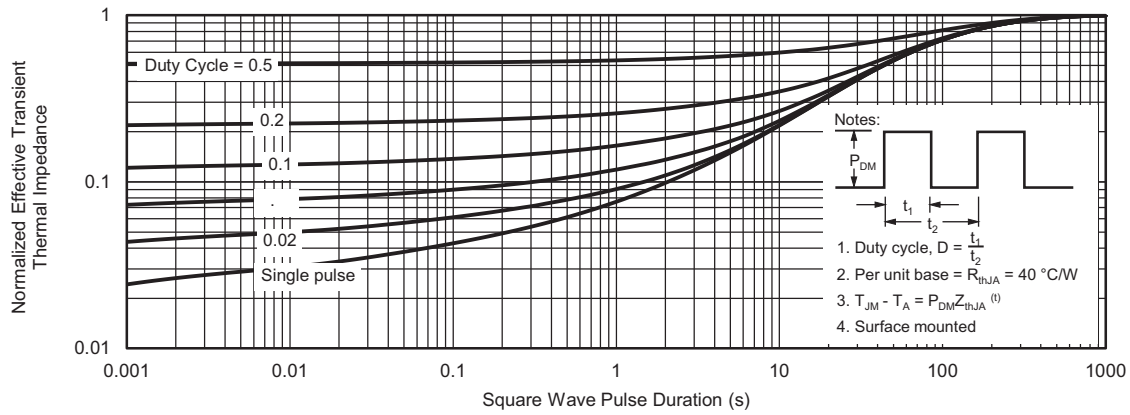


Current De-Rating

THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)

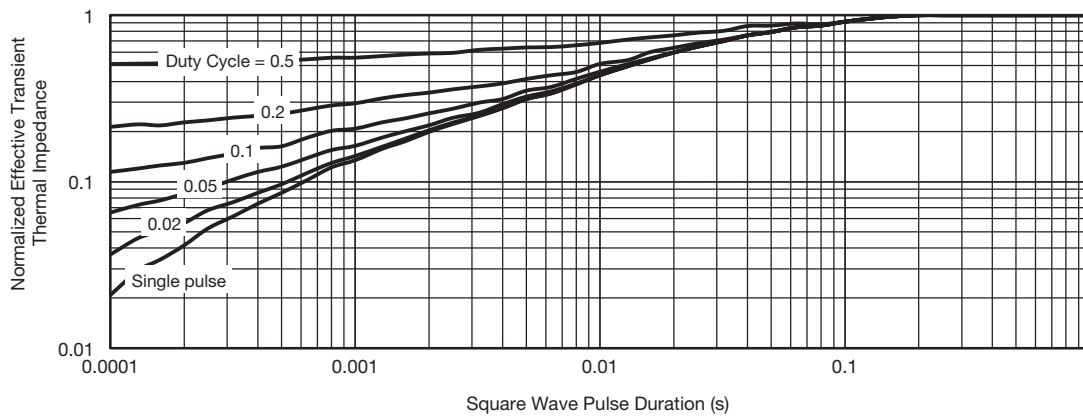


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)

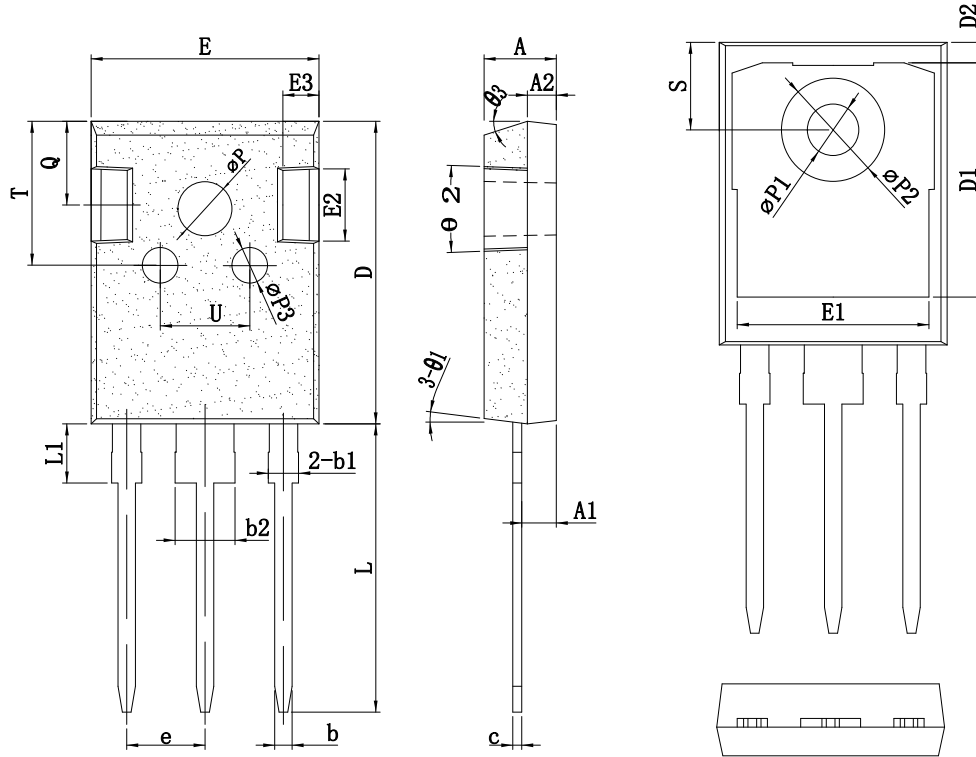


Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction to Case ($25\text{ }^\circ\text{C}$)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

TO-247_3L PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	4.60	5.00	5.40	e	2.10	5.44	5.70
A1	2.10	2.41	2.70	L	19.00	19.98	21.00
A2	1.70	2.00	2.30	L1	-	-	4.50
b	1.00	1.20	1.40	ΦP	3.30	3.70	4.00
b1	1.80	2.10	2.40	$\Phi P1$	3.25	3.55	3.85
b2	2.80	3.10	3.40	$\Phi P2$	6.80	7.18	7.60
C	0.45	0.60	0.75	$\Phi P3$	2.30	2.50	3.30
D	19.00	21.00	23.00	Q	5.50	5.80	6.30
D1	16.00	16.55	17.00	S	5.60	6.15	6.30
D2	0.95	1.20	1.45	T	9.50	10.00	10.50
E	15.70	15.80	16.50	U	6.00	-	8.00
E1	12.80	13.25	13.70	$\theta1$	5°	7°	9°
E2	4.20	5.00	5.30	$\theta2$	1°	3°	5°
E3	2.20	2.50	2.80	$\theta3$	13°	15°	17°

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